

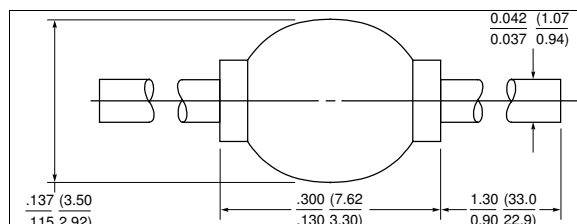
**TECHNICAL DATA**  
**DATA SHEET 167, REV. A****HERMETIC ULTRAFAST RECTIFIER**  
**AXIAL LEAD / SURFACE MOUNT (MELF)****DESCRIPTION:** A 600 VOLT, 2 AMP, 30 NANOSECOND RECTIFIER, IN A HERMETIC PACKAGE.**MAX RATINGS**ALL RATINGS ARE AT  $T_A = 25^{\circ}\text{C}$  UNLESS OTHERWISE SPECIFIED

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	600	Volts
MAXIMUM AVERAGE DC OUTPUT CURRENT ( $T_A = 55^{\circ}\text{C}$ ) ( $T_A = 100^{\circ}\text{C}$ )	$I_O$	2.0 6.0	Amps
PEAK SINGLE CYCLE SURGE CURRENT ( $t_p = 8.3 \text{ ms}$ )	$I_{FSM}$	75	Amps
MAXIMUM THERMAL RESISTANCE, JUNCTION TO LEAD	$R_{\theta JL}$	22	
MAXIMUM THERMAL RESISTANCE, JUNCTION TO END CAP	$R_{\theta JEC}$	8.0	$^{\circ}\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	-	-65 to +175	$^{\circ}\text{C}$

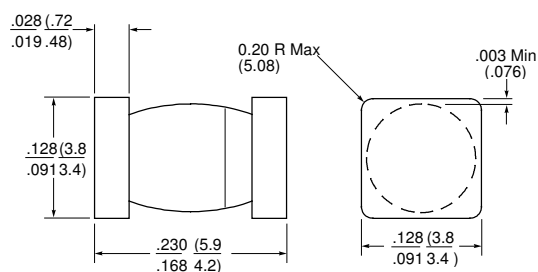
**ELECTRICAL CHARACTERISTICS**

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP ( $I_F = 2.0 \text{ A}$ )	$V_F$	1.35	Volts
MAXIMUM REVERSE CURRENT AT PIV ( $T_A = 25^{\circ}\text{C}$ ) ( $T_A = 100^{\circ}\text{C}$ )	$I_R$	2.0 500	$\mu\text{A}$
MAXIMUM REVERSE RECOVERY TIME ( $I_F = 0.5\text{A}$ , $I_R = 1.0 \text{ A}$ , $I_{RR} = 0.25\text{A}$ )	$t_{rr}$	30	nsec

**MECHANICAL DIMENSIONS - In inches and mm**



**PKG. 306**



**MELF-B**

**Note:** The cathode side is marked on body with a dark band.

**TECHNICAL DATA**

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